

## **BAY73**

### **Small Signal Diode**



DO-35

### Absolute Maximum Ratings \* T<sub>a</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value	Unit
$V_{RRM}$	Maximum Repetitive Reverse Voltage	125	V
I <sub>F(AV)</sub>	Average Rectified Forward Current	500	mA
I <sub>FSM</sub>	Non-repetitive Peak Forward Surge Current Pulse Width = 1.0 second Pulse Width = 1.0 microsecond	1.0 4.0	A A
T <sub>STG</sub>	Storage Temperature Range	-65 to +200	°C
T <sub>J</sub>	Operating Junction Temperature	175	°C

<sup>\*</sup> These ratings are limiting values above which the serviceability of the diode may be impaired.

### **Thermal Characteristics**

Symbol	Parameter	Value	Unit
$P_{D}$	Power Dissipation	500	mW
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	300	°C/W

### Electrical Characteristics T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter	Conditions	Min.	Max	Units
V <sub>R</sub>	Breakdown Voltage	I <sub>R</sub> = 100μA	125		V
V <sub>F</sub>	Forward Voltage	$I_F = 1mA$ $I_F = 5mA$ $I_F = 10mA$ $I_F = 50mA$ $I_F = 100mA$ $I_F = 200mA$	0.60 0.67 0.69 0.78 0.81 0.85	0.68 0.75 0.80 0.88 0.94 1.0	V V V V
I <sub>R</sub>	Reverse Leakage	$V_R = 100V$ $V_R = 100V$ , $T_A = 125$ °C $V_R = 20V$ , $T_A = 125$ °C		5 1 500	nA μA nA
$C_{T}$	Total Capacitance	$V_{R} = 0, f = 1.0MHz$		8	pF
t <sub>rr</sub>	Reverse Recovery Time	$I_F = I_R = 30 \text{mA}, I_{rr} = 3 \text{mA}, R_L = 100 \Omega$		1.0	μs

 $<sup>\</sup>begin{tabular}{ll} \textbf{NOTES:}\\ \textbf{1)} \ These \ ratings \ are \ based \ on \ a \ maximum \ junction \ temperature \ of \ 200 \ degrees \ C. \end{tabular}$ 

<sup>2)</sup> These are steady limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

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